








	<h2 style="color: red;">NTP45N06G</h2>
	<p>Hersteller-Teilenummer: NTP45N06G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 60V 45A TO220AB</p> <hr/> <p>Datenblätter:  NTP45N06G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 23514 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTP45N06G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 45A TO220AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	23514 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (Tj)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	2.4W (Ta), 125W (Tj)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	45A (Ta)
Rds On (Max) @ Id, Vgs	26 mOhm @ 22.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	46nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1725pF @ 25V
Verpackung	Tube



















































NTP45N06G ist neu im Original, Suche NTP45N06G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTP45N06G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTP45N06G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTP35N15G AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 37A TO220AB</p>	 <p>NTP45N06L AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 45A TO220AB</p>	 <p>NTP45N06LG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 45A TO220AB</p>	 <p>NTP477M04TDR NIC NTP477M04TDR NIC</p>
 <p>NTP4302 AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 74A TO220AB</p>	 <p>NTP4813N1LG AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 40A TO220</p>	 <p>NTP45N06 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 45A TO220AB</p>	 <p>NTP5001 HITACHI HITACHI SOP26</p>

heiße Teile

Mehr

 NTP1201A	 NTP1202A	 NTP125N02RG	 NTP13N10	 NTP13N10G
 NTP18N06	 NTP18N06G	 NTP18N06L	 NTP18N06LG	 NTP22N06
 NTP22N06L	 NTP27N06G	 NTP27N06L	 NTP2955G	 NTP30N06L
 NTP30N06LG	 NTP30N20	 NTP30N20G	 NTP35N15	 NTP35N15G
 NTP4302G	 NTP45N06	 NTP45N06L	 NTP45N06LG	 NTP477M04TDR
 NTP52N10	 NTP52N10G	 NTP5404N	 NTP5404NRG	 NTP5411NG
 NTP5412NG	 NTP5426N	 NTP5426NG	 NTP5860N	 NTP5860NG
 NTP5860NL	 NTP5860N1G	 NTP5862NG	 NTP5863N	 NTP5863NG
 NTP5864N	 NTP5864NG	 NTP60N06	 NTP60N06G	 NTP60N06L
 NTP60N06LG	 NTP6410AN	 NTP6410ANG	 NTP6411AN	 NTP6411ANG

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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